N-Channel Enhancement Mode MOSFET

Description

The HBSS123NH6327XTSA1 uses advanced trench technology

to provide excellent $R_{\text{DS}(\text{ON})}$, This device is suitable

for use as a load switch or in PWM applications.

General Features

 $V_{DS} = 100V, I_{D} = 0.17A$

 $R_{DS(ON)} < 6 \Omega @ V_{GS} = 10V$

ESD Rating: 1500V HBM

Application

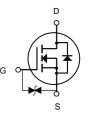
Battery protection

Load switch

Uninterruptible power supply



SOT-23 (TO-236-3)



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HBSS123NH6327XTSA1	SOT-23(TO-236-3)	SA	3000

Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

Symbol	pol Parameter		Unit	
V _{DS}	Drain-Source Voltage	100	V	
Vgs	Gate-Source Voltage	±20	V	
l _D	Drain Current-Continuous	0.17	Α	
l	Drain Current-Pulsed (Note 1)	0.68	А	
P _D	Maximum Power Dissipation	0.35	W	
ТЈ,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	°C	
ReJA Thermal Resistance,Junction-to-Ambient (Note 2)		350	°C/W	

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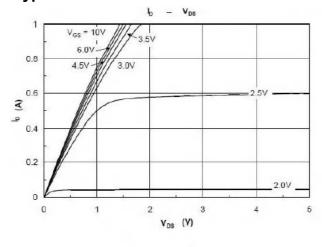
Electrical Characteristics (T_A=25°C unless otherwise noted)

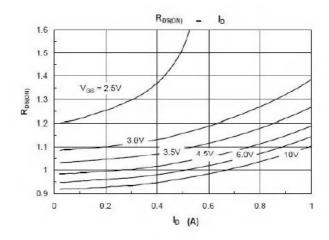
Symbol	Parameter	Test conditions	Мn	Тур	Max	Unit	
Static	Static						
V _{(BR)DSS}	Drain-source breakdown voltage	V_{GS} =0, I_{D} =250 μ A	100			V	
$V_{GS(th)}$	Gate threshold voltage	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.5		2.5	V	
I _{GSS}	Gate-body leakage current	V _{DS} =0, V _{GS} =±20V			±10	μA	
I _{DSS}	Zero gate voltage drain current	V _{DS} =100V, V _{GS} =0V			1	μA	
R _{DS(on)}	Drain course on registance	V _{GS} =10V, I _D =0.17A			6.0	Ω	
	Drain-source on-resistance ^a	V _{GS} =4.5V, I _D =0.17A			9.0	Ω	
V _{SD}	Diode forward voltage	I _S =0.2A,V _{GS} =0V			1.0	V	
Dynamic							
C _{iss}	Input capacitance			30			
Coss	Output capacitance	V _{DS} =50V, V _{GS} =0V, f=1MHz		10		pF	
Crss	Reverse transfer capacitance ^b			7			
Switching	Switching ^b						
t _{d(on)}	Turn-on delay time			1.7			
t _r	Rise time	V _{GS} =10V,V _{DS} =50V		9		200	
t _{d(off)}	Turn-off delay time	I_D =200mA, R_{GEN} =6 Ω		17		nS	
t _f	Fall time]		7			

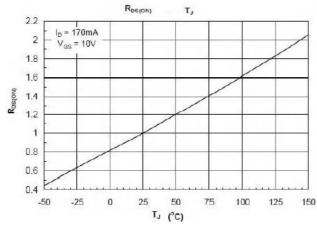
Notes

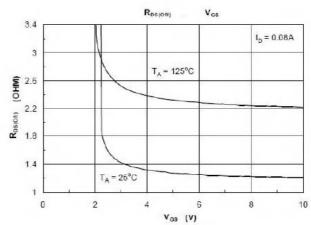
- a. Pulse Test : Pulse width≤300µs, duty cycle ≤2%.
- b. Guaranteed by design, not subject to producting.

TypicalCharacteristics

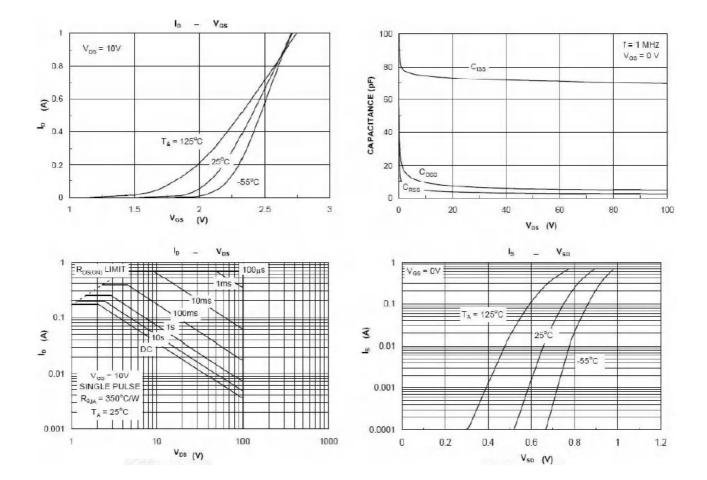




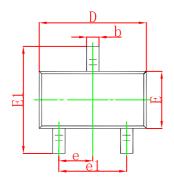


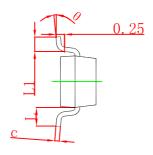


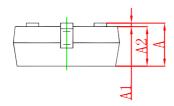
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SOT-23 (TO-236-3) Package Outline Dimensions

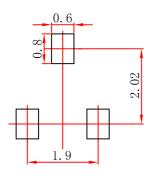






Cumhal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	0.950 TYP 0.037 TYP		7 TYP	
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23(TO-236-3) Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



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